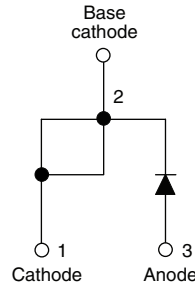


## Fast Soft Recovery Rectifier Diode, 10 A



TO-220AC



### FEATURES/DESCRIPTION

The 10ETF.. fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level.

### APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

PRODUCT SUMMARY	
$V_{RRM}$	200 to 600 V
$V_F$ at 10 A	< 1.2 V
$t_{rr}$	50 ns

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$V_{RRM}$		200 to 600	V
$I_{F(AV)}$	Sinusoidal waveform	10	A
$I_{FSM}$		150	
$t_{rr}$	1 A, 100 A/ $\mu$ s	50	ns
$V_F$	10 A, $T_J = 25^\circ\text{C}$	1.2	V
$T_J$		- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS			
PART NUMBER	$V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ AT 150 $^\circ\text{C}$ mA
10ETF02	200	300	2
10ETF04	400	500	
10ETF06	600	700	

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 128^\circ\text{C}$ , 180 $^\circ$ conduction half sine wave	10	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	10 ms sine pulse, rated $V_{RRM}$ applied	150	
		10 ms sine pulse, no voltage reapplied	160	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied	112.5	$\text{A}^2\text{s}$
		10 ms sine pulse, no voltage reapplied	160	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	1600	$\text{A}^2\sqrt{\text{s}}$

# 10ETF.. Soft Recovery Series

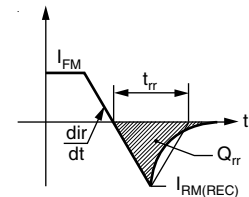


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Fast Soft Recovery  
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	10 A, $T_J = 25\text{ }^\circ\text{C}$		1.2	V
Forward slope resistance	$r_t$	$T_J = 150\text{ }^\circ\text{C}$		23.5	$m\Omega$
Threshold voltage	$V_{F(TO)}$			0.85	V
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		3.0	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	$t_{rr}$	$I_F$ at 10 Apk 25 A/ $\mu\text{s}$ $25\text{ }^\circ\text{C}$	145	ns
Reverse recovery current	$I_{rr}$		2.75	A
Reverse recovery charge	$Q_{rr}$		0.32	$\mu\text{C}$
Snap factor	S		0.6	



THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 40 to 150	$^\circ\text{C}$
Maximum thermal resistance junction to case	$R_{thJC}$	DC operation	1.5	$^\circ\text{C/W}$
Maximum thermal resistance junction to ambient	$R_{thJA}$		62	
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-220AC (JEDEC)	10ETF02	
			10ETF04	
			10ETF06	



# 10ETF.. Soft Recovery Series

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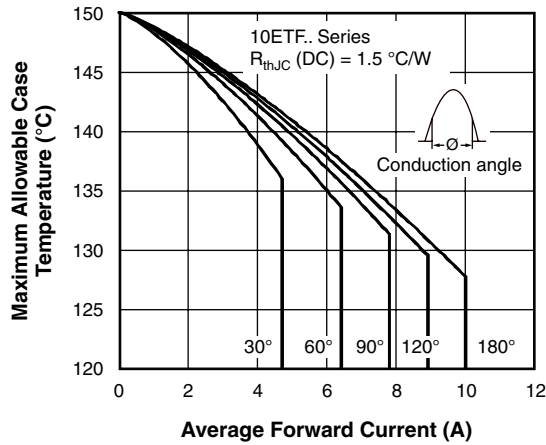


Fig. 1 - Current Rating Characteristics

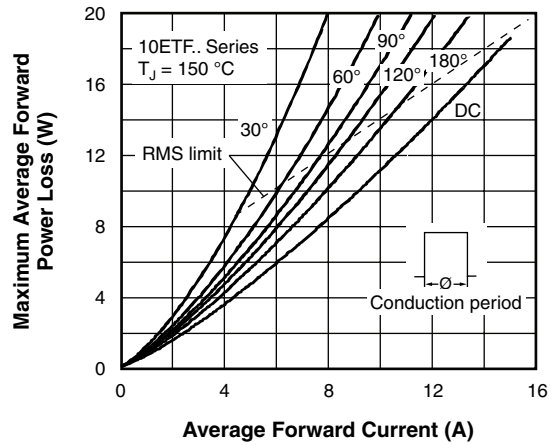


Fig. 4 - Forward Power Loss Characteristics

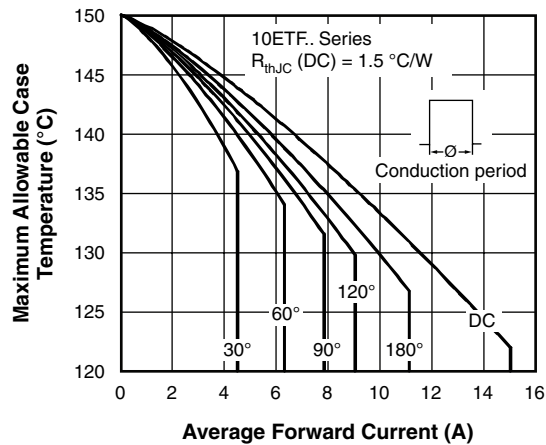


Fig. 2 - Current Rating Characteristics

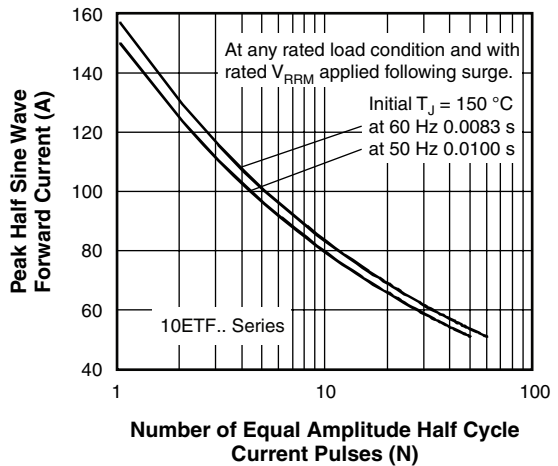


Fig. 5 - Maximum Non-Repetitive Surge Current

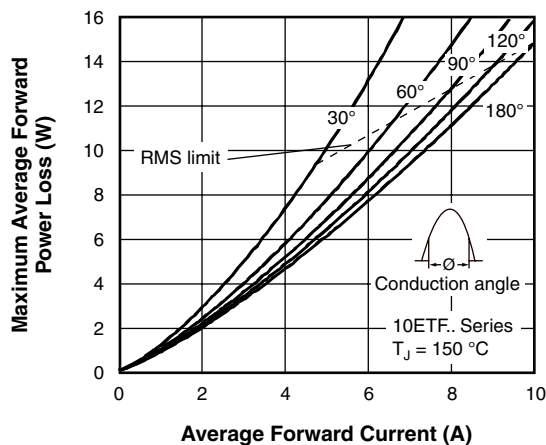


Fig. 3 - Forward Power Loss Characteristics

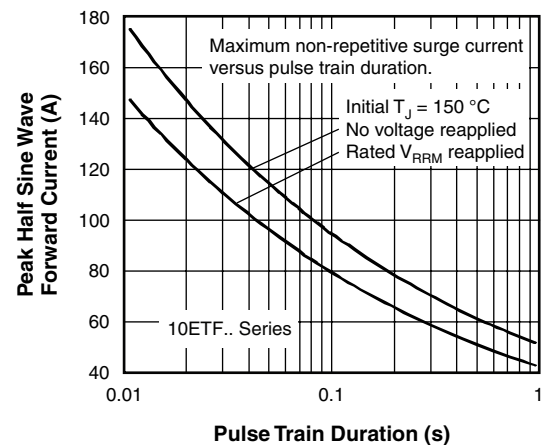


Fig. 6 - Maximum Non-Repetitive Surge Current

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Fast Soft Recovery Rectifier Diode, 10 A

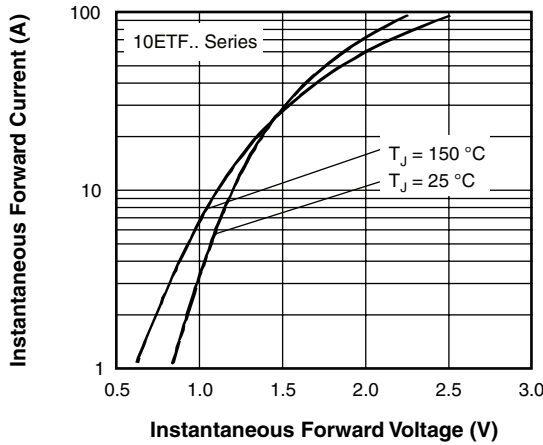


Fig. 7 - Forward Voltage Drop Characteristics

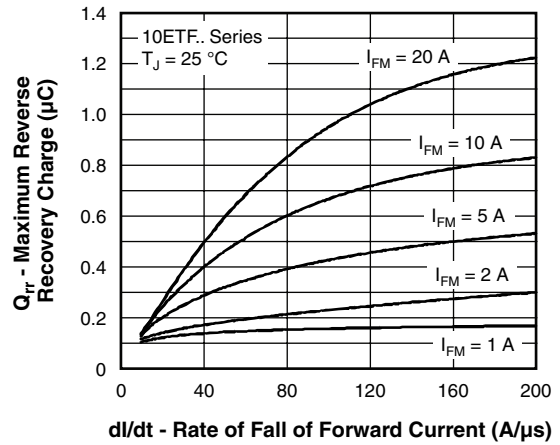


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

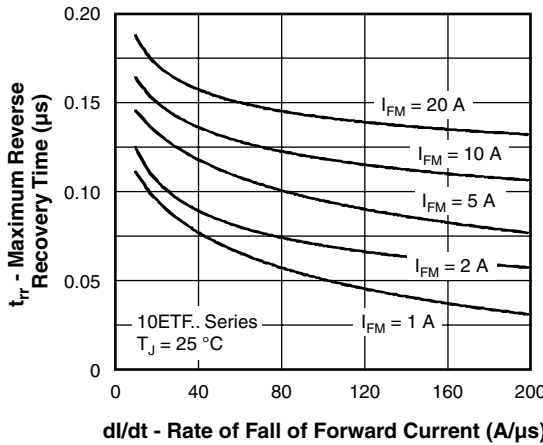


Fig. 8 - Recovery Time Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

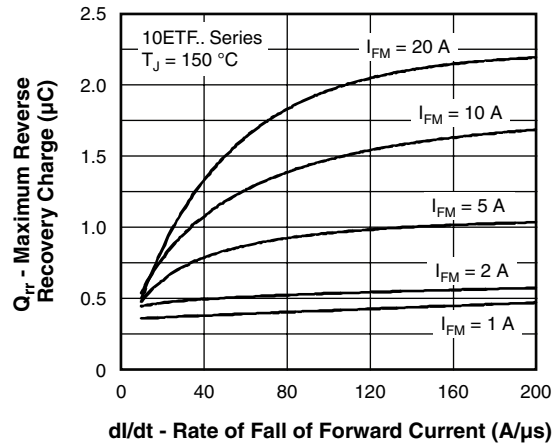


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

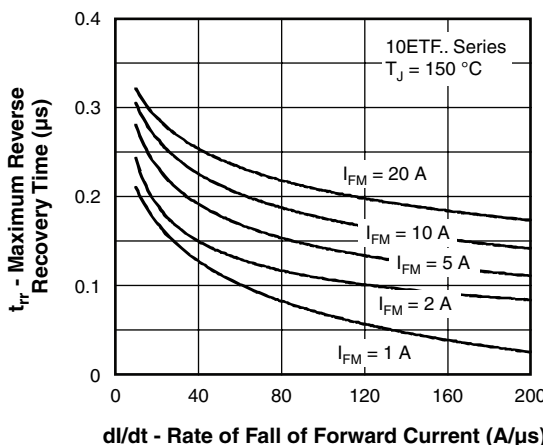


Fig. 9 - Recovery Time Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

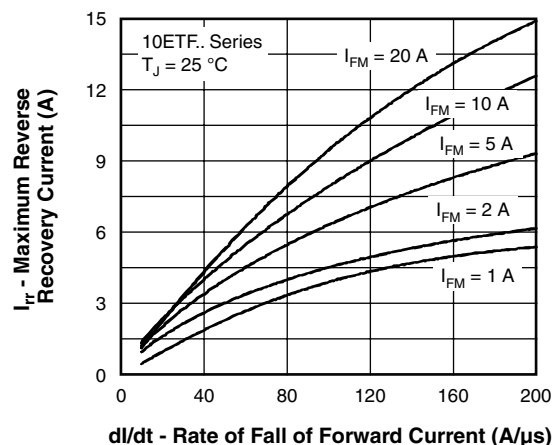


Fig. 12 - Recovery Current Characteristics,  $T_J = 25\text{ }^\circ\text{C}$



# 10ETF.. Soft Recovery Series

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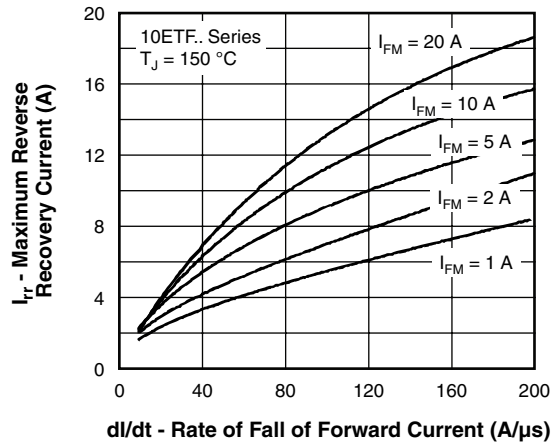


Fig. 13 - Recovery Current Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

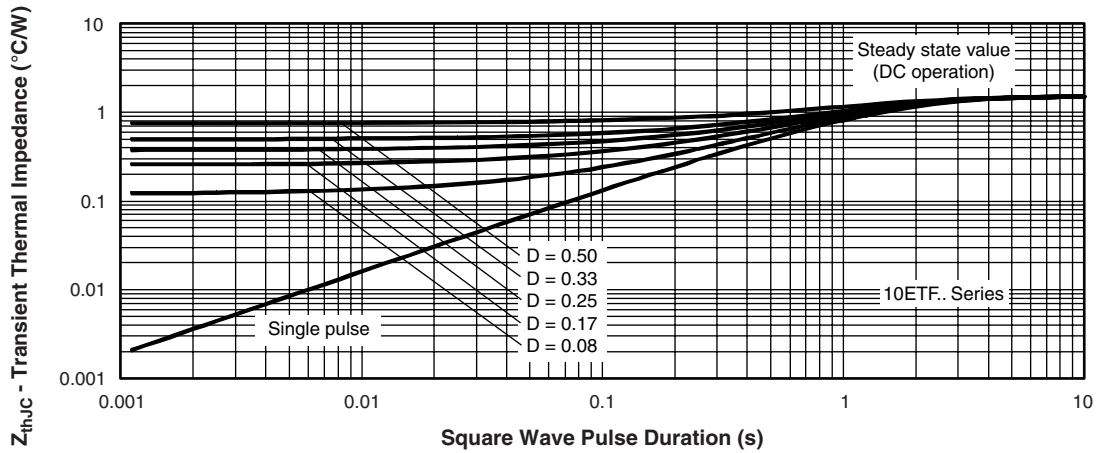


Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics

# 10ETF.. Soft Recovery Series

Vishay High Power Products

Fast Soft Recovery  
Rectifier Diode, 10 A



## ORDERING INFORMATION TABLE

Device code	10	E	T	F	06	-
	①	②	③	④	⑤	⑥
<b>1</b>	-	Current rating (10 = 10 A)				
<b>2</b>	-	Circuit configuration: E = Single diode				
<b>3</b>	-	Package: T = TO-220AC				
<b>4</b>	-	Type of silicon: F = Fast soft recovery rectifier				
<b>5</b>	-	Voltage code x 100 = $V_{RRM}$				
<b>6</b>	-	• None = Standard production • PbF = Lead (Pb)-free				

02 = 200 V  
04 = 400 V  
06 = 600 V

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95221">http://www.vishay.com/doc?95221</a>
Part marking information	<a href="http://www.vishay.com/doc?95224">http://www.vishay.com/doc?95224</a>



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[>>Vishay\(威世\)](#)